

To our customers,

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## Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: <http://www.renesas.com>

April 1<sup>st</sup>, 2010  
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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Phase-out/Discontinued

SWITCHING  
N-CHANNEL POWER MOS FET  
INDUSTRIAL USE

DESCRIPTION

The 2SK2486 is N-Channel MOS Field Effect Transistor designed for high voltage switching applications.

FEATURES

- Low On-Resistance  
 $R_{DS(on)} = 2.0 \Omega$  ( $V_{GS} = 10 V, I_D = 4.0 A$ )
- Low  $C_{iss}$   $C_{iss} = 1830 pF$  TYP.
- High Avalanche Capability Ratings

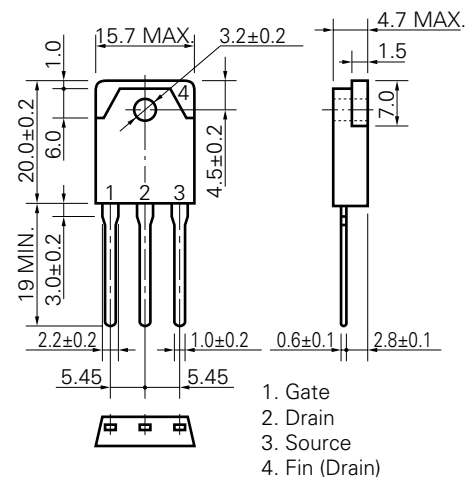
ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ C$ )

Drain to Source Voltage	$V_{DSS}$	900	V
Gate to Source Voltage	$V_{GSS}$	$\pm 30$	V
Drain Current (DC)	$I_D(DC)$	$\pm 7.0$	A
Drain Current (pulse)*	$I_D(pulse)$	$\pm 18$	A
Total Power Dissipation ( $T_c = 25^\circ C$ )	$P_{T1}$	120	W
Total Power Dissipation ( $T_A = 25^\circ C$ )	$P_{T2}$	3.0	W
Channel Temperature	$T_{ch}$	150	$^\circ C$
Storage Temperature	$T_{stg}$	-55 to +150	$^\circ C$
Single Avalanche Current**	$I_{AS}$	7.0	A
Single Avalanche Energy**	$E_{AS}$	144.1	mJ

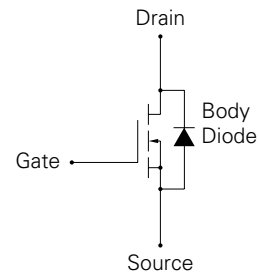
\*  $PW \leq 10 \mu s, Duty Cycle \leq 1\%$

\*\* Starting  $T_{ch} = 25^\circ C, R_G = 25 \Omega, V_{GS} = 20 V \rightarrow 0$

PACKAGE DIMENSIONS  
(in millimeter)



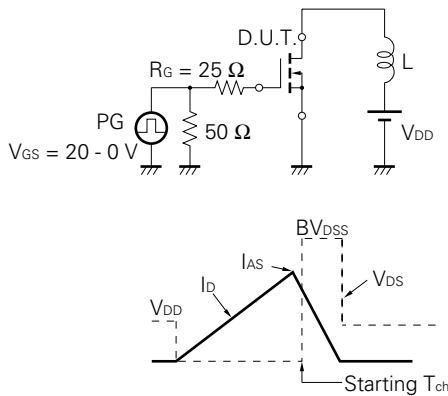
MP-88



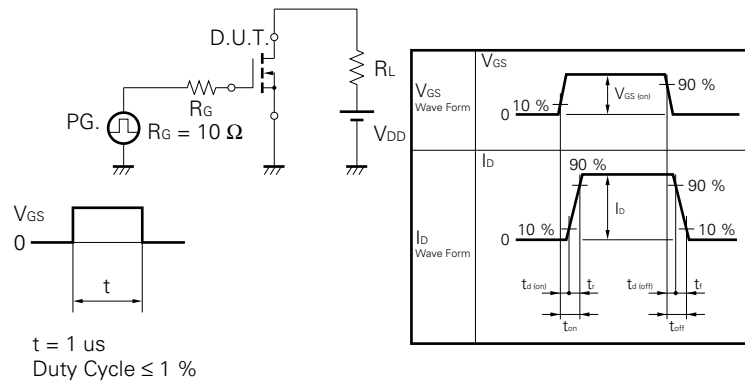
**ELECTRICAL CHARACTERISTICS (Ta = 25 °C)**

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain to Source On-Resistance	$R_{DS(on)}$		1.4	2.0	$\Omega$	$V_{GS} = 10\text{ V}, I_D = 4.0\text{ A}$
Gate to Source Cutoff Voltage	$V_{GS(off)}$	2.5		3.5	V	$V_{DS} = 10\text{ V}, I_D = 1\text{ mA}$
Forward Transfer Admittance	$ y_{fs} $	2.5			S	$V_{DS} = 20\text{ V}, I_D = 4.0\text{ A}$
Drain Leakage Current	$I_{DSS}$			100	$\mu\text{A}$	$V_{DS} = V_{DSS}, V_{GS} = 0$
Gate to Source Leakage Current	$I_{GSS}$			$\pm 100$	nA	$V_{GS} = \pm 30\text{ V}, V_{DS} = 0$
Input Capacitance	$C_{iss}$		1 830		pF	$V_{DS} = 10\text{ V}$
Output Capacitance	$C_{oss}$		250		pF	$V_{GS} = 0$
Reverse Transfer Capacitance	$C_{rss}$		40		pF	$f = 1\text{ MHz}$
Turn-On Delay Time	$t_{d(on)}$		30		ns	$I_D = 4.0\text{ A}$
Rise Time	$t_r$		15		ns	$V_{GS} = 10\text{ V}$
Turn-Off Delay Time	$t_{d(off)}$		110		ns	$V_{DD} = 150\text{ V}$
Fall Time	$t_f$		20		ns	$R_G = 10\ \Omega$
Total Gate Charge	$Q_G$		55		nC	$I_D = 7.0\text{ A}$
Gate to Source Charge	$Q_{GS}$		10		nC	$V_{DD} = 450\text{ V}$
Gate to Drain Charge	$Q_{GD}$		25		nC	$V_{GS} = 10\text{ V}$
Body Diode Forward Voltage	$V_{F(S-D)}$		1.0		V	$I_F = 7.0\text{ A}, V_{GS} = 0$
Reverse Recovery Time	$t_{rr}$		800		ns	$I_F = 7.0\text{ A}, V_{GS} = 0$
Reverse Recovery Charge	$Q_{rr}$		4.8		$\mu\text{C}$	$di/dt = 50\text{ A}/\mu\text{s}$

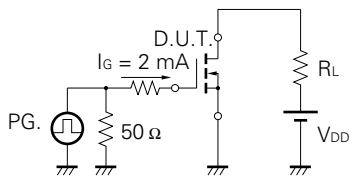
**Test Circuit 1 Avalanche Capability**



**Test Circuit 2 Switching Time**

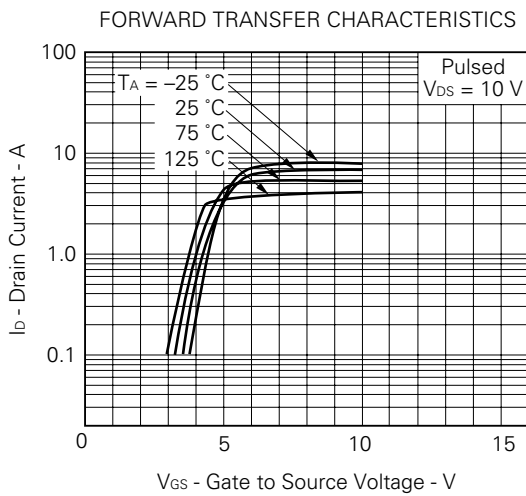
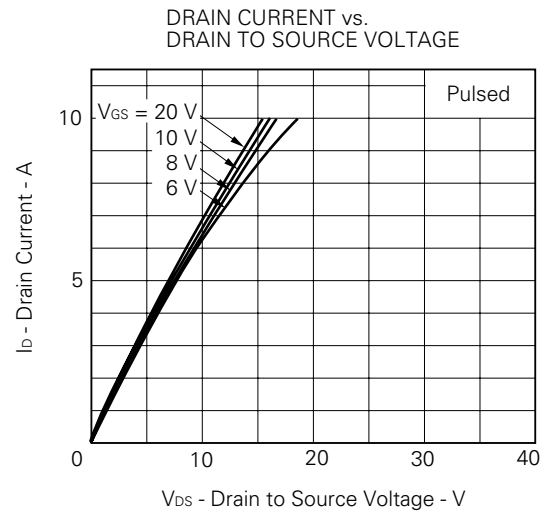
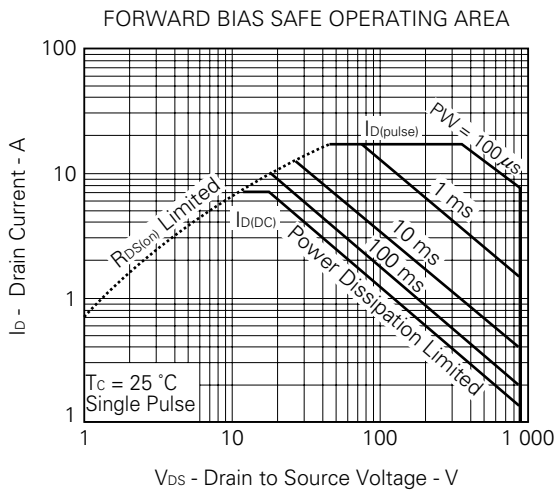
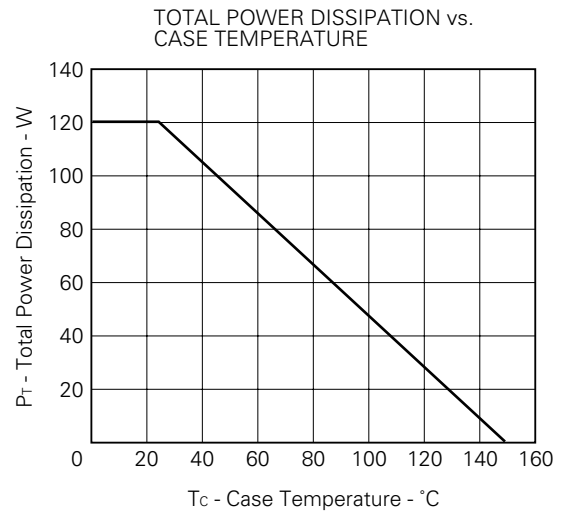
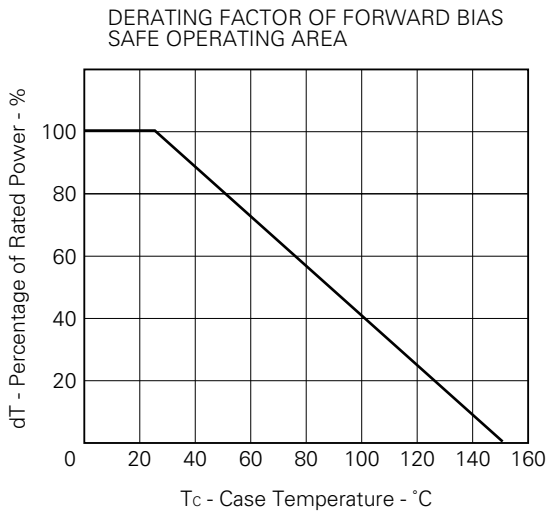


**Test Circuit 3 Gate Charge**

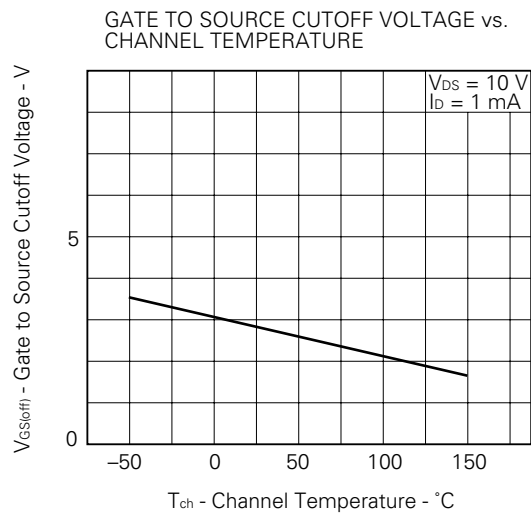
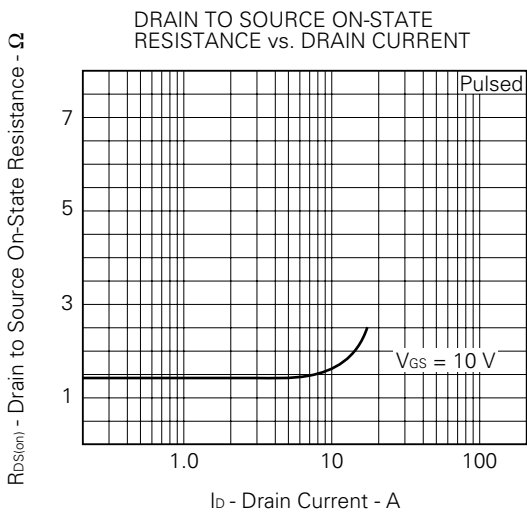
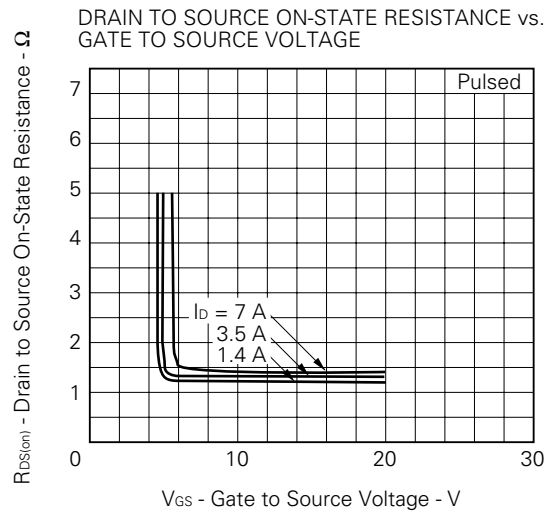
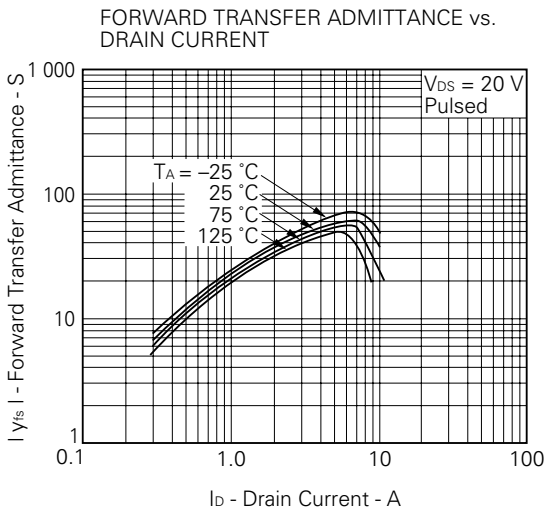
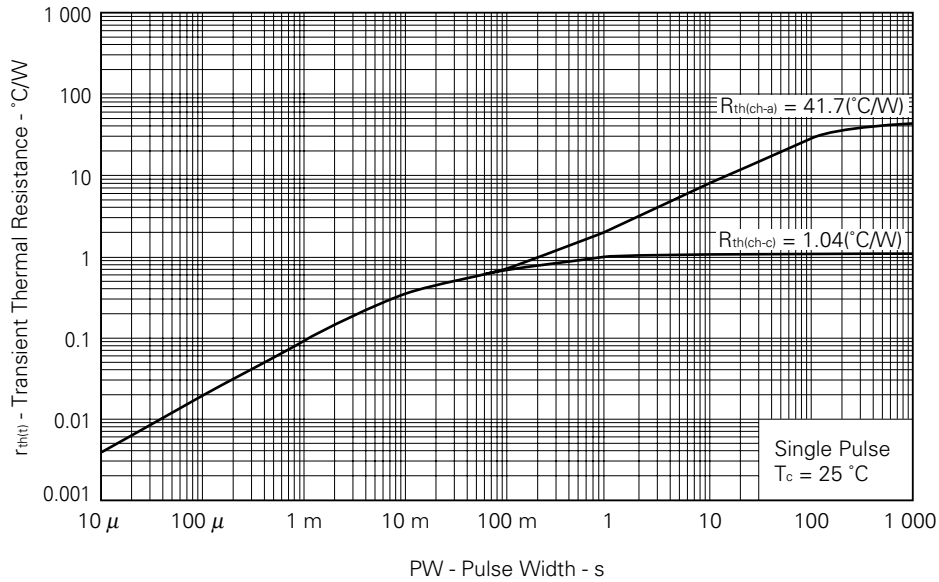


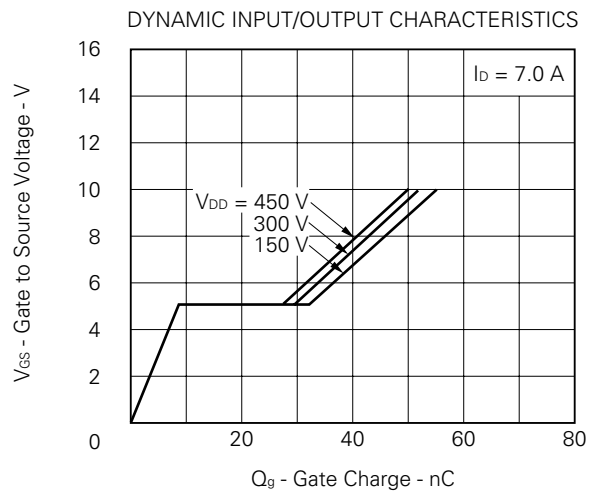
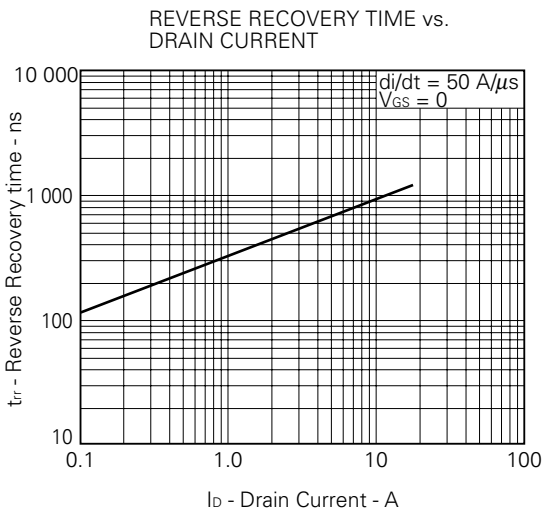
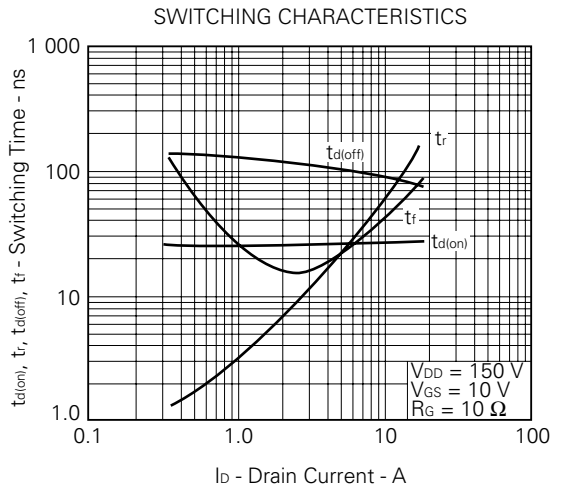
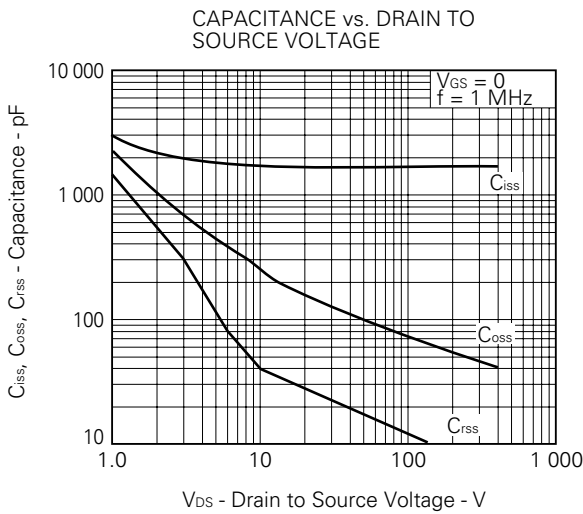
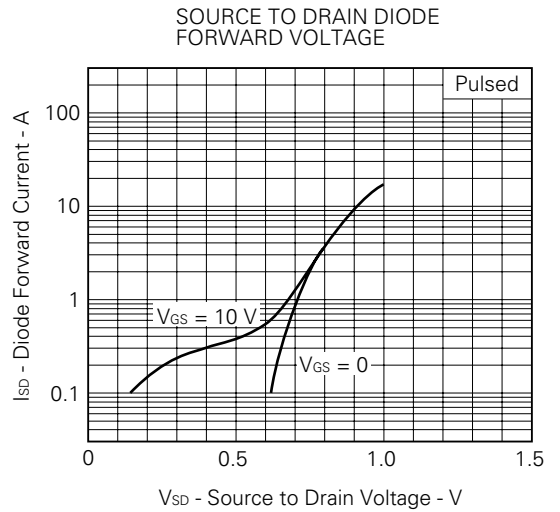
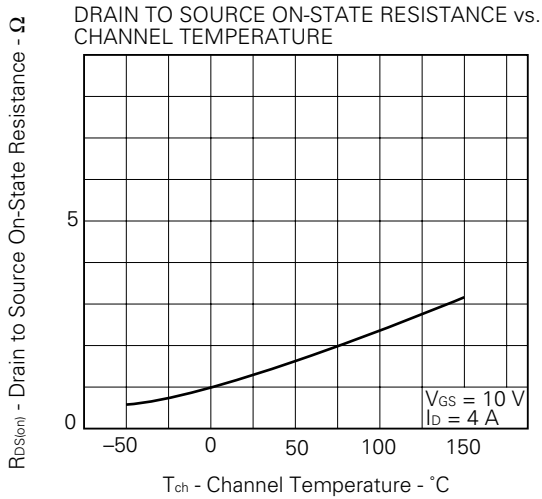
The application circuits and their parameters are for references only and are not intended for use in actual design-in's.

**TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C)**

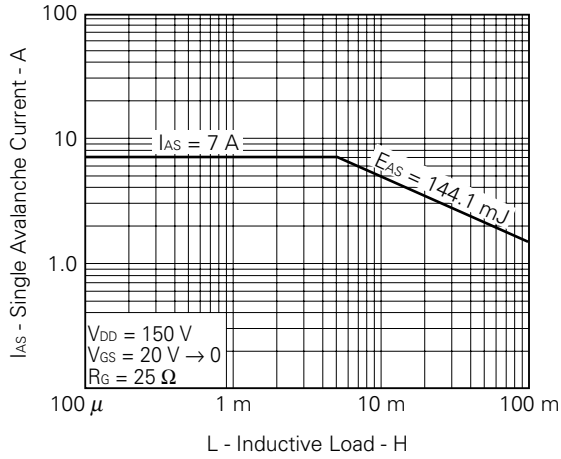


TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

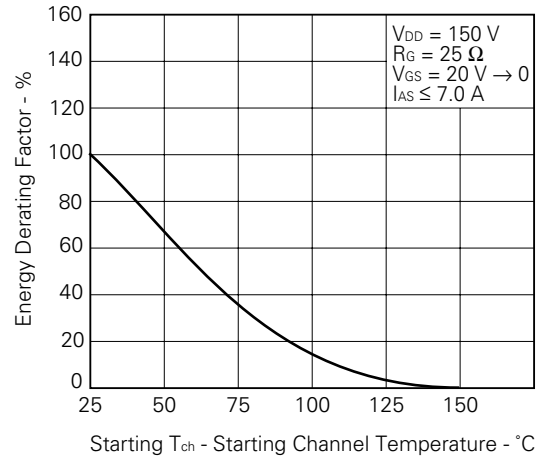




SINGLE AVALANCHE CURRENT vs. INDUCTIVE LOAD



SINGLE AVALANCHE ENERGY DERATING FACTOR





**REFERENCE**

Document Name	Document No.
NEC semiconductor device reliability/quality control system.	TEI-1202
Quality grade on NEC semiconductor devices.	IEI-1209
Semiconductor device mounting technology manual.	IEI-1207
Semiconductor device package manual.	IEI-1213
Guide to quality assurance for semiconductor devices.	MEI-1202
Semiconductor selection guide.	MF-1134
Power MOS FET features and application switching power supply.	TEA-1034
Application circuits using Power MOS FET.	TEA-1035
Safe operating area of Power MOS FET.	TEA-1037

[MEMO]

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Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)

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